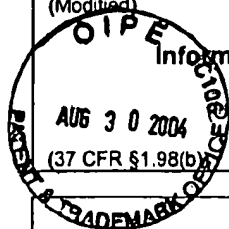


Substitute Form PTO-1449
(Modified)U.S. Department of Commerce
Patent and Trademark OfficeAttorney's Docket No.
16459-010001Application No.
10/724,029**Information Disclosure Statement
by Applicant**

(Use several sheets if necessary)

Applicant
Alexei A. ErchakFiling Date
November 26, 2003Group Art Unit
2879**U.S. Patent Documents**

| Examiner Initial | Desig. ID | Document Number | Publication Date | Patentee | Class | Subclass | Filing Date If Appropriate |
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| | AE | | | | | | |
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| Examiner Initial | Desig. ID | Document Number | Publication Date | Country or Patent Office | Class | Subclass | Translation | |
|------------------|-----------|-----------------|------------------|--------------------------|-------|----------|-------------|----|
| | | | | | | | Yes | No |
| | AL | | | | | | | |
| | AM | | | | | | | |
| | AN | | | | | | | |
| | AO | | | | | | | |
| | AP | | | | | | | |

Other Documents (include Author, Title, Date, and Place of Publication)

| Examiner Initial | Desig. ID | Document |
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| | AQ | |
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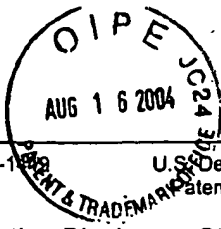
Examiner Signature

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Date Considered

11/09/04

EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.



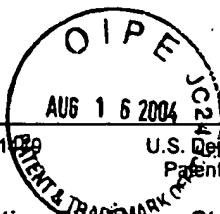
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| | Applicant Alexei A. Erchak | | |
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| | | | | | | | Yes | No |
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Sheet 2 of 2

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| | Applicant Alexei A. Erchak | | |
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